

DOCKET NO. : LIN 13-38

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

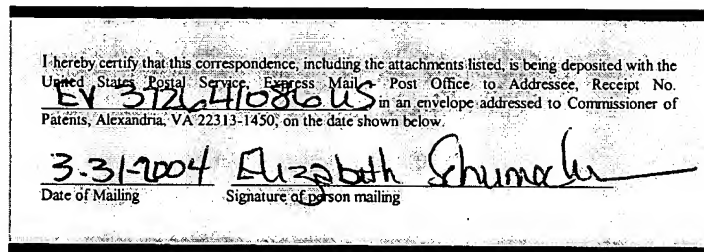
In re application of:

Wen Lin, et al.

For:

SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE
MATCHING LAYER AND A METHOD OF MANUFACTURE
THEREFOR

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450



Sir:

PRELIMINARY AMENDMENT

Before examination of the above-identified application, please amend it as follows:

IN THE SPECIFICATION

Please amend the specification by inserting before the first line the sentence:

--This Application is a Divisional of prior Application Serial No. 10/003,873 filed on October 24, 2001, currently pending, to Wen Lin, et al.. The above-listed Application is commonly assigned with the present invention and is incorporated herein by reference as if reproduced herein in its entirety under Rule 1.53(b).--